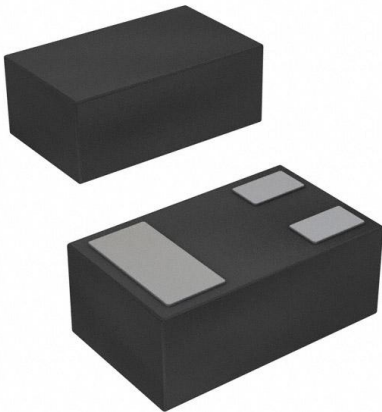


2SA207900A Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SA207900A-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SA207900A
Description	TRANS PNP 45V 0.1A ML3-N2
Detailed Description	Bipolar (BJT) Transistor PNP 45 V 100 mA 80MHz 100 mW Surface Mount ML3-N2



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

2SA207900A

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

45 V

Current - Collector Cutoff (Max):

100µA

Power - Max:

100 mW

Operating Temperature:

125°C (TJ)

Package / Case:

SC-101, SOT-883

Base Product Number:

2SA2079

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

500mV @ 10mA, 100mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

180 @ 2mA, 10V

Frequency - Transition:

80MHz

Mounting Type:

Surface Mount

Supplier Device Package:

ML3-N2

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0095

ECCN:

EAR99

2SA2079

Silicon PNP epitaxial planar type

For general amplification
 Complementary to 2SC5848

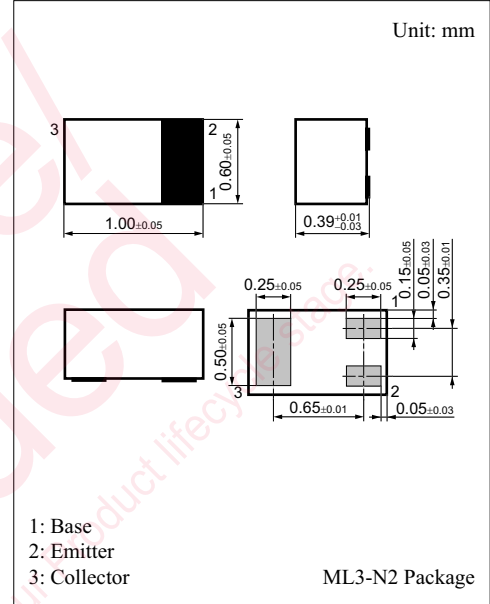
■ Features

- High forward current transfer ratio h_{FE}
- Suitable for high-density mounting and downsizing of the equipment for ultraminiature leadless package

Package: 0.6 mm × 1.0 mm (height 0.39 mm)

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	-45	V
Collector-emitter voltage (Base open)	V_{CEO}	-45	V
Emitter-base voltage (Collector open)	V_{EBO}	-7	V
Collector current	I_C	-100	mA
Peak collector current	I_{CP}	-200	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

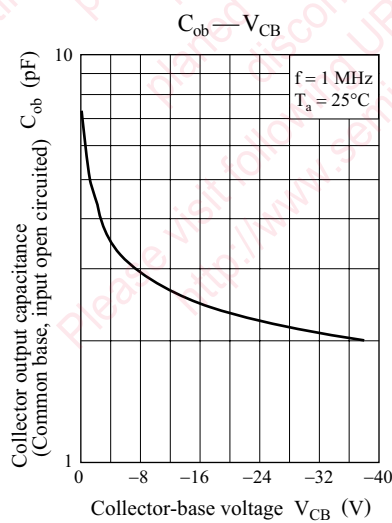
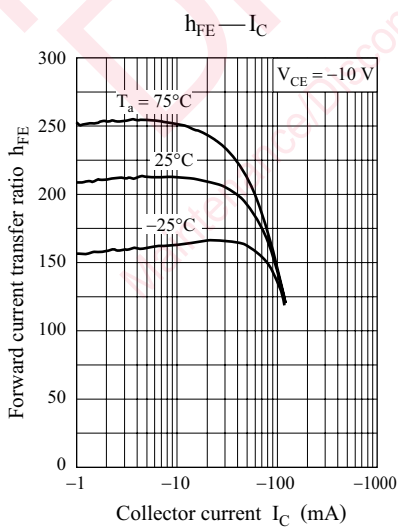
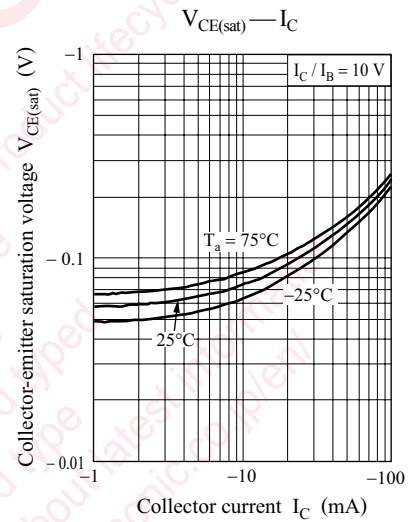
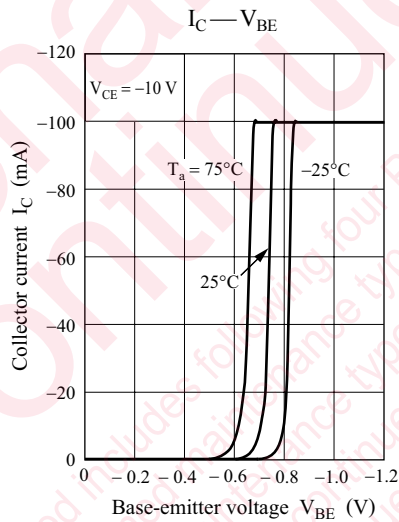
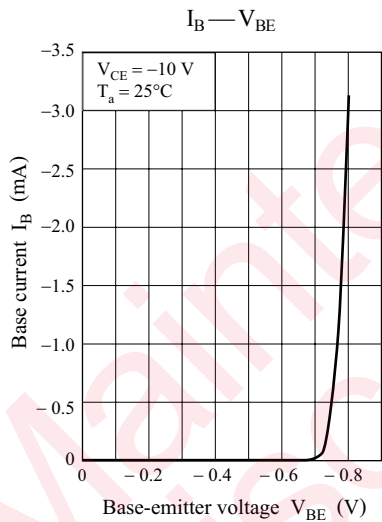
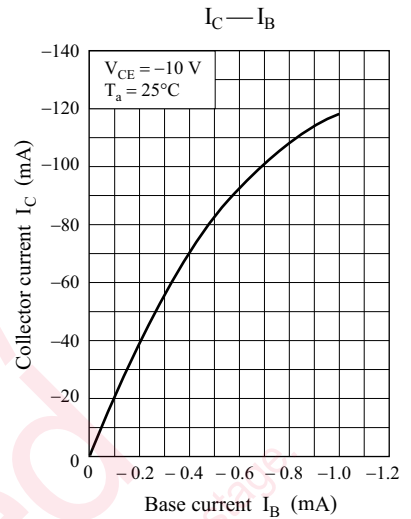
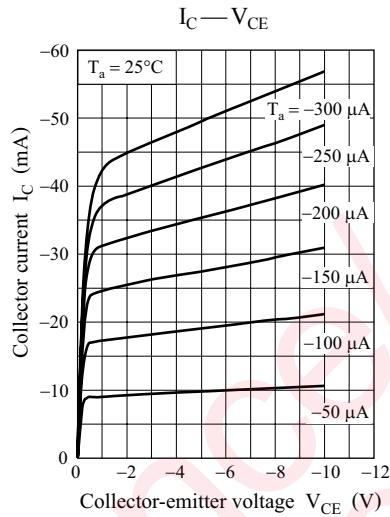
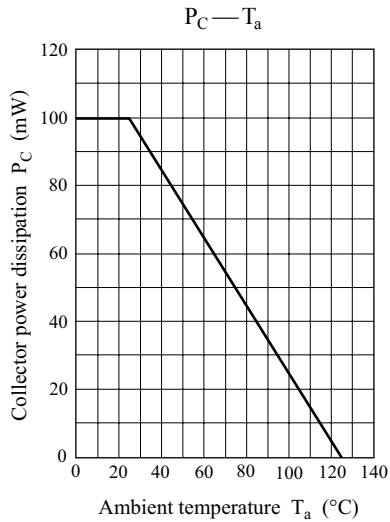


Marking Symbol : 3D

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-45			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-45			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = -10 \mu\text{A}, I_C = 0$	-7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			-0.1	μA
Collector-emitter cut-off current (Base open)	I_{CEO}	$V_{CE} = -10 \text{ V}, I_B = 0$			-100	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$	180		390	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$		-0.2	-0.5	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.2		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



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